

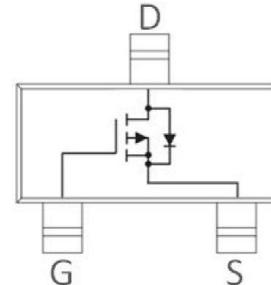
### P-Channel MOSFET

#### FEATURES

- ◊ Epoxy meets UL 94 V-0 flammability rating
- ◊ High density cell design for low RDS(ON)
- ◊ Trench Power LV MOSFET technology

#### APPLICATIONS

- ◊ Battery management
- ◊ High speed switch
- ◊ Low power DC to DC converter
- ◊ Marking: A19T



Package: SOT-23-3L

#### ABSOLUTE MAXIMUM RATING (Tamb=25°C)

Symbol	Parameter	Value	Units
V <sub>DS</sub>	Drain-Source Voltage	-30	V
V <sub>GS</sub>	Gate-Source Voltage	±12	V
I <sub>D</sub>	Continuous Drain Current	-4.2	A
I <sub>DM</sub>	Drain Current-Pulsed	-16.8	A
P <sub>D</sub>	Total Power Dissipation	400	mW
T <sub>J</sub> & T <sub>stg</sub>	Junction Temperature and Storage Temperature	-55 to 150	°C
R <sub>θJA</sub>	Thermal Resistance From Junction To Ambient	350	°C/W

#### ELECTRICAL CHARACTERISTICS (Tamb=25°C)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
V <sub>(BR)DSS</sub>	Drain-Source Voltage Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	-30			V
V <sub>GS(th)</sub>	Gate-Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	-0.7		-1.3	V
I <sub>GSS</sub>	Gate-Body Leakage	V <sub>DS</sub> =0V, V <sub>GS</sub> =±12V			100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V			1	µA
R <sub>DS(on)</sub>	Drain-Source On-Resistance ①	V <sub>GS</sub> =-10V, I <sub>D</sub> =-4.2A V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1A		40 60	60 80 110	mΩ
V <sub>SD</sub>	Diode Forward Voltage	V <sub>GS</sub> =0V, I <sub>S</sub> =-3A			-1.1	V

**Dynamic Characteristics (Tamb=25°C)**

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
Ciss	Input Capacitance②	$V_{DS}=-15V$ $V_{GS}=0V$ $f=1MHz$		950		pF
Coss	Output Capacitance②			115		
Crss	Reverse Transfer Capacitance②			77		

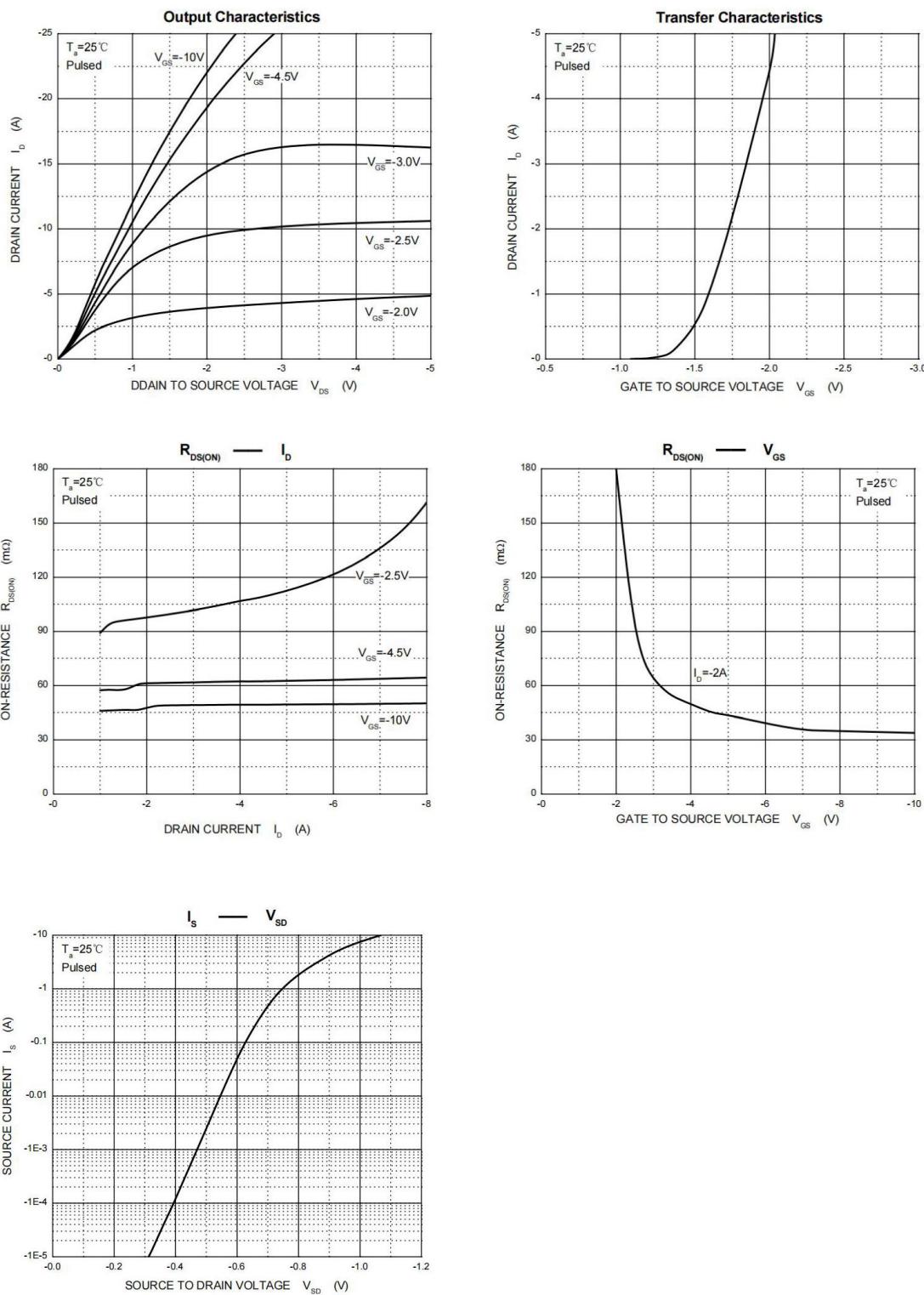
**Switching Characteristics (Tamb=25°C)**

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
$t_{d(on)}$	Turn on Delay Time	$V_{GS}=-10V, V_{DS}=-15V,$ $R_L=3.6\Omega, R_{GEN}=6\Omega$		6.3		nS
$t_r$	Turn-on Rise Time			3.2		
$t_{d(off)}$	Turn off Delay Time			38		
$t_f$	Turn-off Fall Time			12		

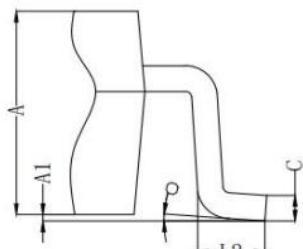
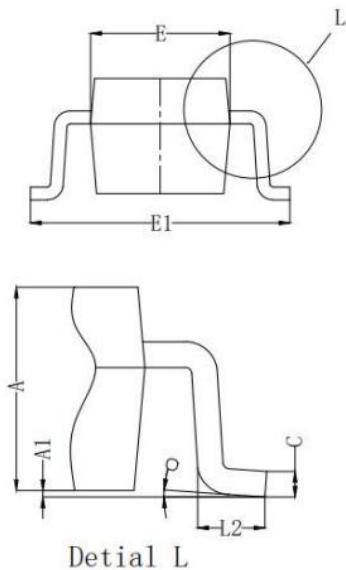
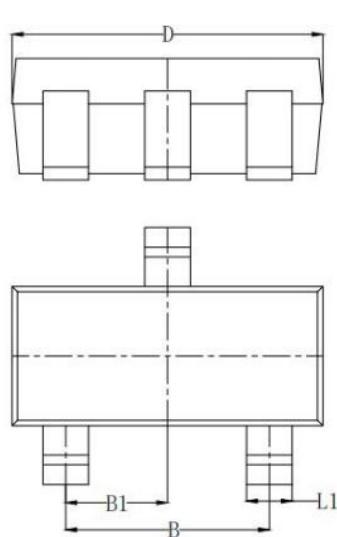
Note:

- ① Pulse test: Pulse width≤300μS, duty cycle≤2%.
- ② These parameters have no way to verify.

### ELECTRICAL CHARACTERISTICS CURVE



## SOT-23-3L PACKAGE OUTLINE DIMENSIONS



Symbol	Dim in mm		
	Min	Nom	Max
A	1.050	1.100	1.150
A1	0.000	0.050	0.100
L1	0.300	0.400	0.500
C	0.100	0.150	0.200
D	2.820	2.920	3.020
E	1.500	1.600	1.700
E1	2.650	2.800	2.950
B	1.800	1.900	2.000
B1	0.950 TYP		
L2	0.300	0.450	0.600
o	0°	4°	8°